

SO1T6C2.5V1

产品编码 (MODEL ID): STMO10
文件编号 (DOCUMENT): STM-CPGGS075
版本号 (VERSION): A3

制作日期 (DATE): 2003.9.12
页数 (PAGE): 1 OF 4



产品描述 Features:

- 多量程霍尔闭环电流传感器
Closed loop (compensated) multirange current transducer using the Hall effect
- 原边副边之间绝缘
With a galvanic isolation between the primary circuit and secondary circuit
- 用于测量直流、交流、脉冲电流
For the electronic measurement of current DC,AC,pulsed
- 单电源供电
Unipolar voltage supply
- PCB 安装
Compact design for PCB mounting

特性 Advantages:

- 出色的精度
Excellent accuracy
- 良好的线性度
Very good linearit
- 响应时间快
Optimized response time
- 优良的温度特性
Very low temperature drift
- 无插入损耗
No insertion losses
- 抗干扰能力强
High immunity to external interference

应用 Applications:

- 交流变频调速
AC variable speed drives
- 伺服电机牵引
servo motor drives
- 不间断电源 (UPS)
Uninterruptible power supplies
- 电池电源
Battery supplied applications
- 开关电源 (SMPS)
Switched mode power Supplies
- 电焊机电源
Power supplies for welding applications

电参数 Electrical data:

IPN	原边额定输入电流 Primary nominal current rms	6	A
IP	原边测量电流范围 Primary current measuring range	0... ± 19.2	A
Vout	副边额定输出电压 Output voltage	IP 2.5 ± (0.625 × IP / IPN)	V
		IP=0	2.5 ± 0.025
G	灵敏度 Sensitivity	IPN	104.16 mV/A
Ns	副边匝数 Number of secondary turns (±0.1%)	2000T	
Vc	电源电压 power supply (±5%)	5	V
Ic	电流消耗 Current consumption, Vc=5V	Typ 12+ Is ^{1>} (Vout/ RL)	mA
RL	负载阻值 Load resistance	≥ 2	K Ω
RIM	内测电阻 In measuring resisance (±0.5%)	208.3	Ω
TCRIM	内测电阻温漂 Thermal drift of RIM	< 50	ppm/k
Vd	工频耐压 R.m.s.voltage for AC isolation test	50/60HZ 1min	3 KV

精度—动态参数 Accuracy— Dynamic performance data:

Ae	精度 Accuracy@ IPN	TA=25°C	≤ ± 0.2	%
AG	总精度 Accuracy with RIM @ IPN	TA=25°C	≤ ± 0.7	%
Le	线性度 Linearity		< 0.1	%
TCVOUT	输出电压温漂 Thermal drift of Vout @	-10...+85°C	80	200 ppm/k
		-40...-10°C		250 ppm/k
TCEG	灵敏度温漂 Thermal drift of G	-40...+85 °C	50 ^{2>}	ppm/k
VOM	剩余电压 Magnetic offset voltage @ IP=0, 经过过载 after an overload of	3x IPN	± 0.5	mV
		5x IPN	± 2.0	mV
		10x IPN	± 2.0	mV
Tra	响应时间 Reaction time@10% of IPN		< 100	ns
Tr	响应时间 Response time to 90% of IPN step		< 400	ns
di/dt	di/dt 跟随精度 di/dt accurately followed		> 15	A/us
F	频带宽度 Frequency bandwidth	0...-0.5dB	DC...100	KHZ
		-0.5...1dB	DC...200	KHZ

一般参数 General data

TA	工作环境温度 Ambient operating temperature	-40...+85	°C
TS	存储环境温度 Ambient storage temperature	-40...+90	°C
RS	次级线圈电阻 Secondary coil resistance	47	Ω
m	重量 Mass	10	g
	塑件 Material	PC, UL94V0	
	标准 Standards	prEN 50178	

1> IS= IP/ NS

2> Only due to TCRIM

SO1T15C2.5V1

产品编码 (MODEL ID): STM005

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版本号 (VERSION): A3

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Switched mode power Supplies
- 电焊机电源
Power supplies for welding applications

电参数 Electrical data:

IPN	原边额定输入电流 Primary nominal current rms	15	A
IP	原边测量电流范围 Primary current measuring range	0... ± 48	A
Vout	副边额定输出电压 Output voltage	IP 2.5 ± (0.625 × IP / IPN)	V
		IP=0 2.5 ± 0.025	V
G	灵敏度 Sensitivity	IPN 41.6	mV/A
Ns	副边匝数 Number of secondary turns (±0.1%)	1200T	
Vc	电源电压 power supply (±5%)	5	V
Ic	电流消耗 Current consumption, Vc=5V	Typ 12 + Is ^{1>} + (Vout / RL)	mA
RL	负载阻值 Load resistance	≥ 2	K Ω
RIM	内测电阻 In measuring resistance (±0.5%)	50	Ω
TCRIM	内测电阻温漂 Thermal drift of RIM	< 50	ppm/k
Vd	工频耐压 R.m.s.voltage for AC isolation test	50/60HZ 1min 3	KV

精度—动态参数 Accuracy— Dynamic performance data:

Ae	精度 Accuracy @ IPN	TA=25°C	≤ ±0.2	%	
Ag	总精度 Accuracy with RIM @ IPN	TA=25°C	≤ ±0.7	%	
Le	线性度 Linearity		< 0.1	%	
TCVout	输出电压温漂 Thermal drift of Vout @	-10...+85°C	TYP 65	MAX 120	ppm/k
		-40...-10°C	65	170	ppm/k
TCEg	灵敏度温漂 Thermal drift of G	-40...+85 °C	50 ^{2>}	ppm/k	
Vom	剩余电压 Magnetic offset voltage @ IP=0, 经过过载 after an overload of	3x IPN	±0.5	mV	
		5x IPN	±2.0	mV	
		10x IPN	±2.0	mV	
Tra	响应时间 Reaction time @ 10% of IPN		< 100	ns	
Tr	响应时间 Response time to 90% of IPN step		< 400	ns	
di/dt	di/dt 跟随精度 di/dt accurately followed		> 35	A/us	
F	频带宽度 Frequency bandwidth	0...-0.5dB	DC...100	KHZ	
		-0.5...1dB	DC...200	KHZ	

一般参数 General data

TA	工作环境温度 Ambient operating temperature	-40...+85	°C
Ts	存储环境温度 Ambient storage temperature	-40...+90	°C
Rs	次级线圈电阻 Secondary coil resistance	26	Ω
m	重量 Mass	10	g
	塑件 Material	PC, UL94V0	
	标准 Standards	prEN 50178	

1> IS= IP/ NS

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SO1T25C2.5V1

产品编码 (MODEL ID): STM004
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Battery supplied applications
- 开关电源 (SMPS)
Switched mode power Supplies
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Power supplies for welding applications

电参数 Electrical data:

IPN	原边额定输入电流 Primary nominal current rms	25	A
IP	原边测量电流范围 Primary current measuring range	0... ±80	A
Vout	副边额定输出电压 Output voltage	IP 2.5 ± (0.625 × IP / IPN)	V
		IP=0	2.5 ± 0.025
G	灵敏度 Sensitivity	IPN	25 mV/A
Ns	副边匝数 Number of secondary turns (±0.1%)	2000T	
Vc	电源电压 power supply (±5%)	5	V
Ic	电流消耗 Current consumption, Vc=5V	Typ 12 + Is ^{1>} × (Vout / RL)	mA
RL	负载阻值 Load resistance	≥2	K Ω
RIM	内测电阻 In measuring resistance (±0.5%)	50	Ω
TCRIM	内测电阻温漂 Thermal drift of RIM	<50	ppm/k
Vd	工频耐压 R.m.s.voltage for AC isolation test	50/60HZ 1min	3 KV

精度—动态参数 Accuracy— Dynamic performance data:

Ae	精度 Accuracy @ IPN	TA=25°C	≤ ±0.2	%	
AG	总精度 Accuracy with RIM @ IPN	TA=25°C	≤ ±0.7	%	
Le	线性度 Linearity		<0.1	%	
TCVOUT	输出电压温漂 Thermal drift of Vout @	-10...+85°C	50	100	ppm/k
		-40...-10°C		150	ppm/k
TCEG	灵敏度温漂 Thermal drift of G	-40...+85 °C	50 ^{2>}	ppm/k	
VOM	剩余电压 Magnetic offset voltage @ IP=0, 经过过载 after an overload of	3x IPN	±0.5	mV	
		5x IPN	±2.0	mV	
		10x IPN	±2.0	mV	
Tra	响应时间 Reaction time @ 10% of IPN		<100	ns	
Tr	响应时间 Response time to 90% of IPN step		<400	ns	
di/dt	di/dt 跟随精度 di/dt accurately followed		>60	A/us	
F	频带宽度 Frequency bandwidth	0...-0.5dB	DC...100	KHZ	
		-0.5...1dB	DC...200	KHZ	

一般参数 General data

TA	工作环境温度 Ambient operating temperature	-40...+85	°C
TS	存储环境温度 Ambient storage temperature	-40...+90	°C
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m	重量 Mass	10	g
	塑件 Material	PC, UL94V0	
	标准 Standards	prEN 50178	

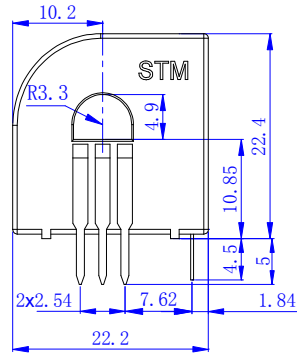
1> IS= IP/ NS

2> Only due to TCRIM

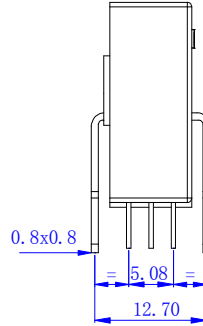
SO1T_C2.5V1

外形图 Mechanical outline (mm)

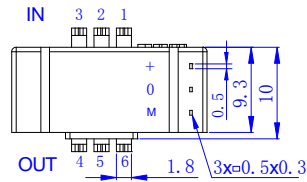
正视图
Front view



左视图
Left view

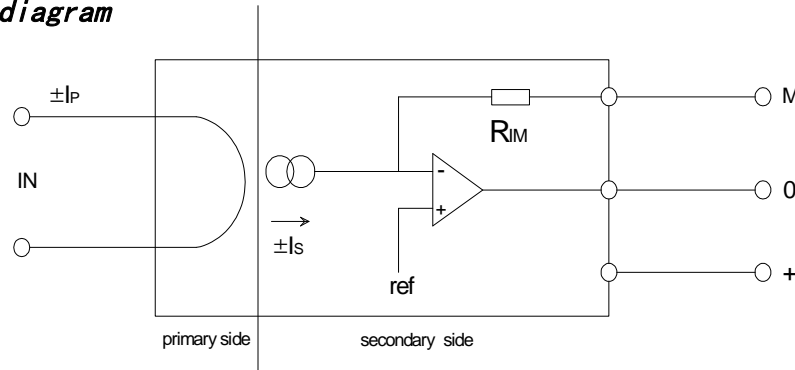


底视图
Bottom view



标识 +	DC+5V
标识 0	GND
标识 M	VSN

接线图 Connection diagram



原边端连接定义 Connection definition

匝数 N	初级额定电流 I_{PN} (A)	额定输出电压 V_{out} (V)	初级电阻 R_P (Ω)	连接点
1	6/15/25	2.5 ± 0.625	0.18	
2	3/7.5/12.5	2.5 ± 0.625	0.81	
3	2/5/8.33	2.5 ± 0.625	1.62	